

LME49713

High Performance, High Fidelity Current Feedback Audio Operational Amplifier

General Description

The LME49713 is an ultra-low distortion, low noise, ultra high slew rate current feedback operational amplifier optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49713 current feedback operational amplifier delivers superior signal amplification for outstanding performance. Operating on a wide supply range of $\pm 5V$ to $\pm 18V$, the LME49713 combines extremely low voltage noise density ($1.9nV/\sqrt{Hz}$) with very low THD+N (0.00008%) to easily satisfy the most demanding applications. To ensure that the most challenging loads are driven without compromise, the LME49713 has a high slew rate of $\pm 1900V/\mu s$ and an output current capability of $\pm 100mA$. Further, dynamic range is maximized by an output stage that drives 150Ω loads to within 2.9V of either power supply voltage.

The LME49713's outstanding CMRR (88dB), PSRR (102dB), and V_{OS} (0.05mV) give the amplifier excellent operational amplifier DC performance.

The LME49713 is available in an 8-lead narrow body SOIC and 8-lead metal can (TO-99). Demonstration boards are available.

Key Specifications

■ Power Supply Voltage Range	$\pm 5V$ to $\pm 18V$
■ THD+N ($A_V = 1$, $R_L = 100\Omega$, $V_{OUT} = 3V_{RMS}$, $f = 1kHz$)	0.0006% (typ)
■ THD+N ($A_V = 1$, $R_L = 600\Omega$, $V_{OUT} = 1.4V_{RMS}$, $f = 1kHz$)	0.00008% (typ)

■ Input Noise Density	$1.9nV/\sqrt{Hz}$ (typ)
■ Slew Rate	$\pm 1900V/\mu s$ (typ)
■ Bandwidth ($A_V = -1$, $R_L = 2k\Omega$, $R_F = 1.2k\Omega$)	132MHz (typ)
■ Input Bias Current	1.8 μA (typ)
■ Input Offset Voltage	0.05mV (typ)

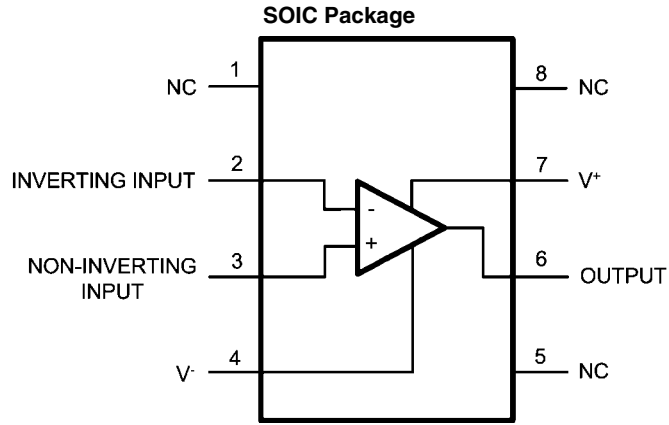
Features

- Easily drives 150Ω loads
- Optimized for superior audio signal fidelity
- Output short circuit protection
- 102dB (typ) PSRR and 88dB (typ) CMRR
- SOIC High Performance and Metal can packages

Applications

- Ultra high quality audio amplification
- High fidelity preamplifiers
- High fidelity multimedia
- State of the art phono pre amps
- High performance professional audio
- High fidelity equalization and crossover networks
- High performance line drivers
- High performance line receivers
- High fidelity active filters

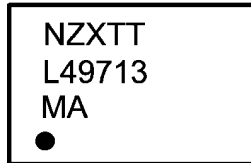
Connection Diagrams



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**Order Number LME49713MA
See NS Package Number M08A**

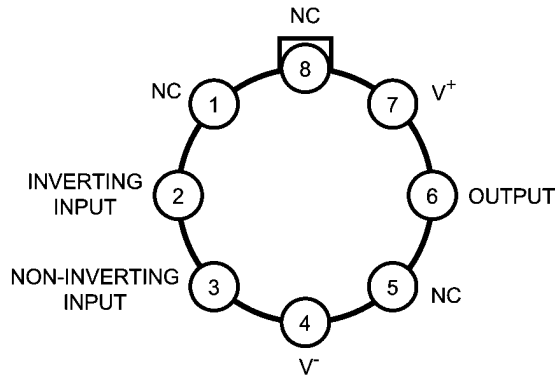
LME49713MA Top Mark



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- N = National Logo**
- Z = Assembly plant code**
- X = 1 Digit date code**
- TT = Die traceability**
- L49713 = LME49713**
- MA = Package code**

Metal Can



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**Order Number LME49713HA
See NS Package Number H08C**

Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Power Supply Voltage ($V_S = V^+ - V^-$)	38V
Storage Temperature	-65°C to 150°C
Input Voltage	(V-) - 0.7V to (V+) + 0.7V
Output Short Circuit (Note 3)	Continuous

Power Dissipation	Internally Limited
ESD Rating (Note 4)	2000V
ESD Rating (Note 5)	200V
Junction Temperature	150°C
Thermal Resistance	
θ_{JA} (MA)	145°C/W
Temperature Range	
$T_{MIN} \leq T_A \leq T_{MAX}$	-40°C $\leq T_A \leq$ 85°C
Supply Voltage Range	$\pm 5.0V \leq V_S \leq \pm 18V$

Electrical Characteristics (Notes 1, 2) The following specifications apply for the $V_S = \pm 15V$, $R_L = 2k\Omega$, $R_{SOURCE} = 10\Omega$, $f_{IN} = 1kHz$, and $T_A = 25^\circ C$, unless otherwise specified.

Symbol	Parameter	Conditions	LME49713		Units (Limits)
			Typical	Limit	
			(Note 6)	(Note 7)	
THD+N	Total Harmonic Distortion + Noise	$A_V = 1$, $V_{OUT} = 3V_{RMS}$, $R_F = 1.2k\Omega$	0.0006	0.00065	% (max)
		$R_L = 100\Omega$, $V_{OUT} = 3V_{RMS}$ $R_L = 600\Omega$, $V_{OUT} = 1.4V_{RMS}$	0.00008	0.0004	% (max)
IMD	Intermodulation Distortion	$A_V = 1$, $V_{IN} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1	0.00009		%
BW	Bandwidth	$A_V = -1$, $R_F = 1.2k\Omega$	132		MHz
SR	Slew Rate	$V_O = 20V_{P-P}$, $A_V = -1$	± 1900		V/ μs
FPBW	Full Power Bandwidth	$V_{OUT} = 20V_{P-P}$, $A_V = -1$	30		MHz
t_s	Settling time	$A_V = -1$, 10V step, 0.1% error range	50		ns
e_n	Equivalent Input Noise Voltage	$f_{BW} = 20Hz$ to 20kHz	0.26	0.6	μV_{RMS} (max)
	Equivalent Input Noise Density	$f = 1kHz$ $f = 10Hz$	1.9 11.5	4.0	nV/ \sqrt{Hz} (max)
i_n	Current Noise Density	$f = 1kHz$ $f = 10Hz$	16 160		pA/ \sqrt{Hz}
V_{OS}	Input Offset Voltage		± 0.05	± 1.0	mV (max)
$\Delta V_{OS}/\Delta Temp$	Average Input Offset Voltage Drift vs Temperature	-40°C $\leq T_A \leq$ 85°C	0.29		$\mu V/^\circ C$
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$V_{SUPPLY} = \pm 5V$ to $\pm 15V$ (Note 8)	102	100	dB (min)
I_B	Input Bias Current	$V_{CM} = 0V$	1.8	6	μA (max)
$\Delta I_{OS}/\Delta Temp$	Input Bias Current Drift vs Temperature	-40°C $\leq T_A \leq$ 85°C			
		Inverting input Non-inverting input	4.5 4.7		nA/ $^\circ C$ nA/ $^\circ C$
I_{OS}	Input Offset Current	$V_{CM} = 0V$	1.3	5	μA (max)
V_{IN-CM}	Common-Mode Input Voltage Range		± 13.5	(V+) - 2.0 (V-) + 2.0	V (min) V (min)
CMRR	Common-Mode Rejection	-10V < V_{cm} < 10V	88	87	dB (min)
Z_{IN}	Non-inverting-input Input Impedance	-10V < V_{cm} < 10V	1.2		M Ω
	Inverting-input Input Impedance	-10V < V_{cm} < 10V	58		Ω
Z_T	Transimpedance	$V_{OUT} = \pm 10V$			
		$R_L = 200\Omega$	4.2	2.0	M Ω (min)
		$R_L = \infty$	4.7	2.65	M Ω (min)
V_{OUTMAX}	Maximum Output Voltage Swing	$R_L = 150\Omega$	± 12.1	± 11.3	V (min)
		$R_L = 600\Omega$	± 12.6	± 12.4	V (min)

Symbol	Parameter	Conditions	LME49713		Units (Limits)
			Typical	Limit	
			(Note 6)	(Note 7)	
I_{OUT}	Output Current	$R_L = 150\Omega, V_S = \pm 18V$	± 100	± 93	mA (min)
I_{OUT-CC}	Instantaneous Short Circuit Current		± 140		mA
R_{OUT}	Output Resistance	$f_{IN} = 5MHz$ Closed-Loop Open-Loop	TBD 10		Ω Ω
I_S	Total Quiescent Current	$I_{OUT} = 0mA$	8	9.5	mA (max)

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the *Absolute Maximum Ratings* or other conditions beyond those indicated in the *Recommended Operating Conditions* is not implied. The *Recommended Operating Conditions* indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: The *Electrical Characteristics* tables list guaranteed specifications under the listed *Recommended Operating Conditions* except as otherwise modified or specified by the *Electrical Characteristics Conditions* and/or Notes. Typical specifications are estimations only and are not guaranteed.

Note 3: Amplifier output connected to GND, any number of amplifiers within a package.

Note 4: Human body model, applicable std. JESD22-A114C.

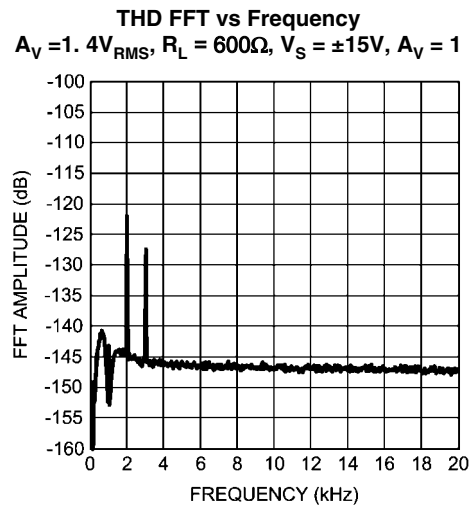
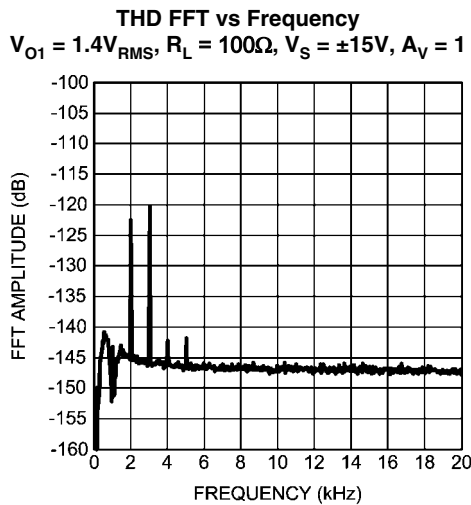
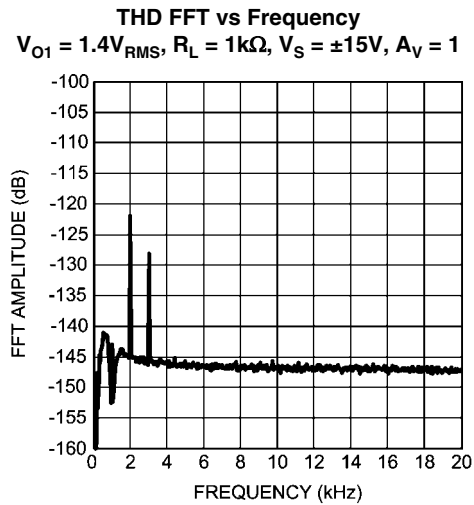
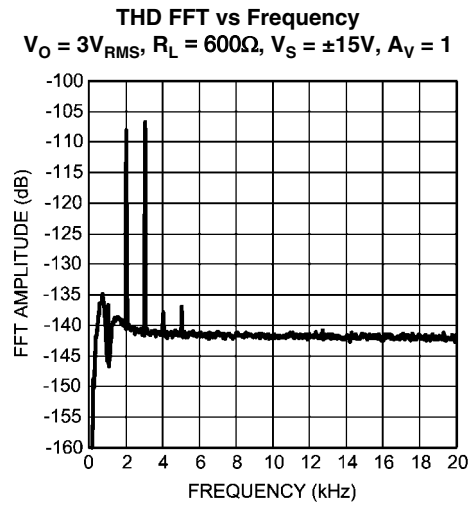
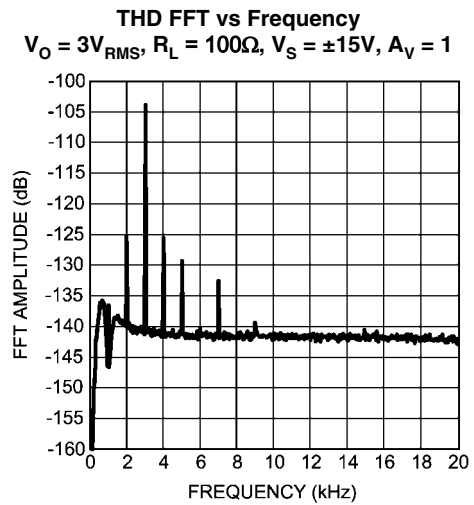
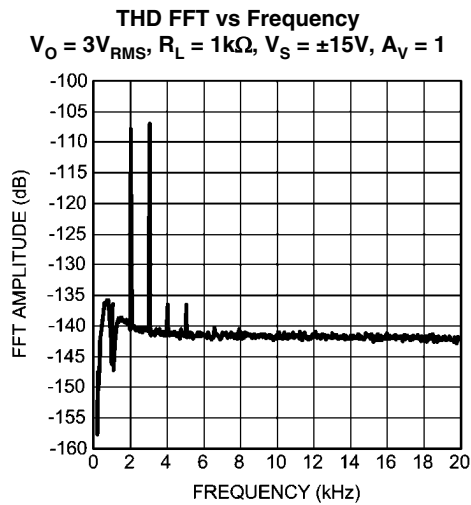
Note 5: Machine model, applicable std. JESD22-A115-A.

Note 6: Typical values represent most likely parametric norms at $T_A = +25^\circ C$, and at the *Recommended Operation Conditions* at the time of product characterization and are not guaranteed.

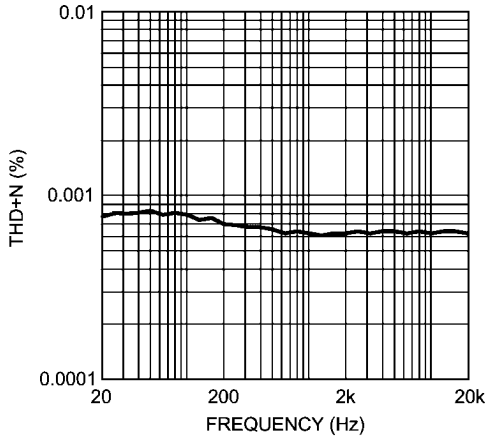
Note 7: Datasheet min/max specification limits are guaranteed by test or statistical analysis.

Note 8: PSRR is measured as follows: V_{OS} is measured at two supply voltages, $\pm 5V$ and $\pm 15V$. $PSRR = |20\log(\Delta V_{OS}/\Delta V_S)|$.

Typical Performance Characteristics

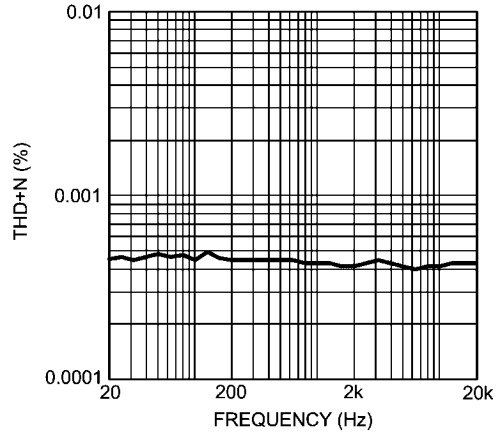


THD vs Frequency
 $V_O = 3V_{RMS}, R_L = 100\Omega, SOIC$



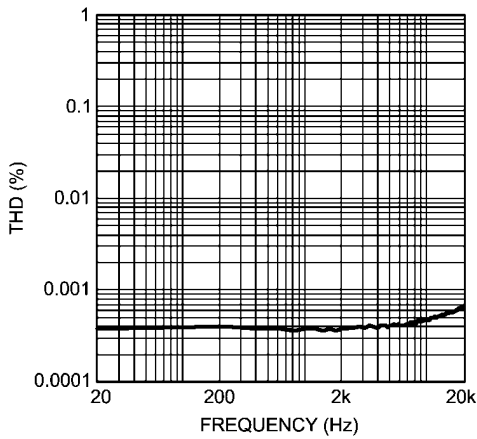
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THD vs Frequency
 $V_O = 3V_{RMS}, R_L = 600\Omega, SOIC$



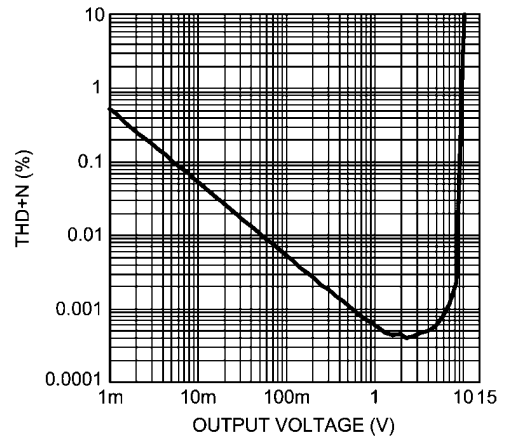
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THD vs Frequency
 $V_O = 3V_{RMS}, R_L = 100\Omega$



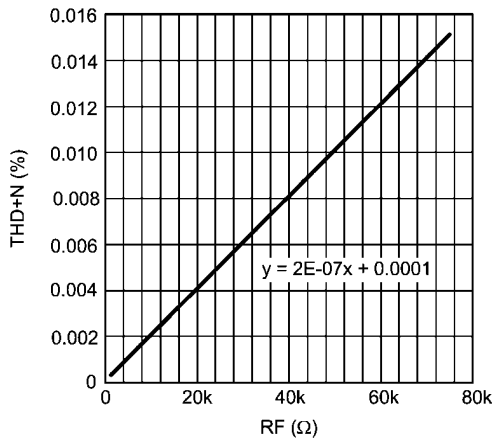
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THD vs Output Voltage
 $V_O = 3V_{RMS}, R_L = 600\Omega$



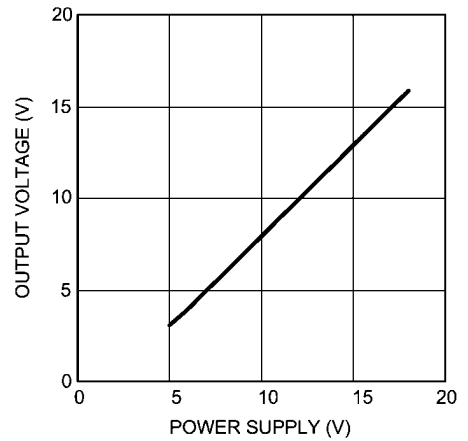
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THD vs RF



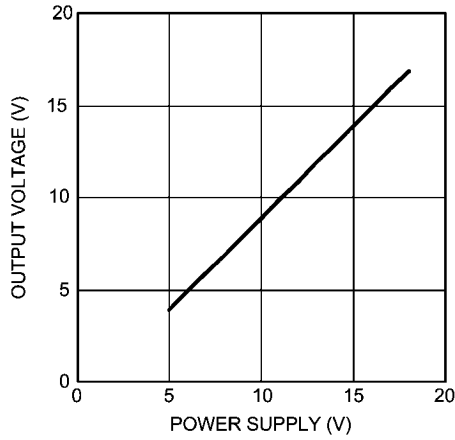
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Output Voltage vs Supply Voltage
 $A_V = 1, R_L = 600\Omega$



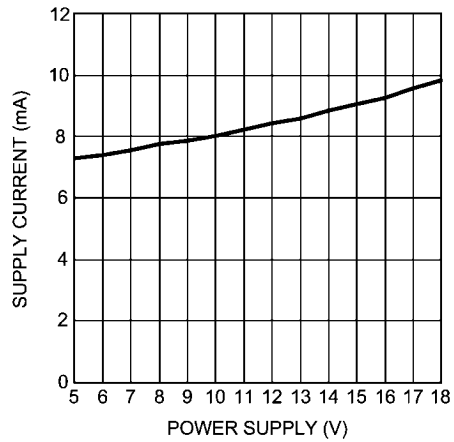
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Output Voltage vs Supply Voltage
 $A_V = 1, R_L = \text{open}$



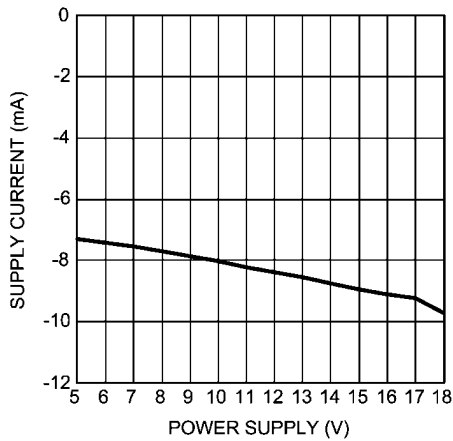
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Supply Current (I_{CC}) vs Power Supply
 $R_L = \text{open}$



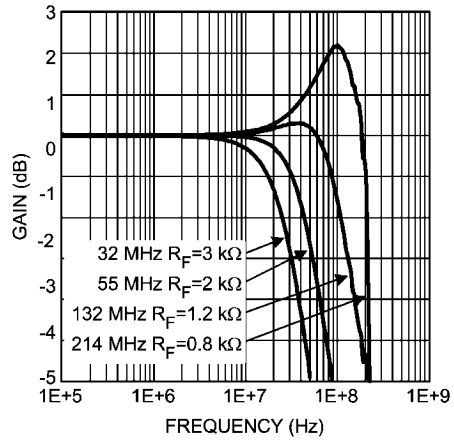
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Supply Current (I_{EE}) vs Power Supply
 $R_L = \text{open}$



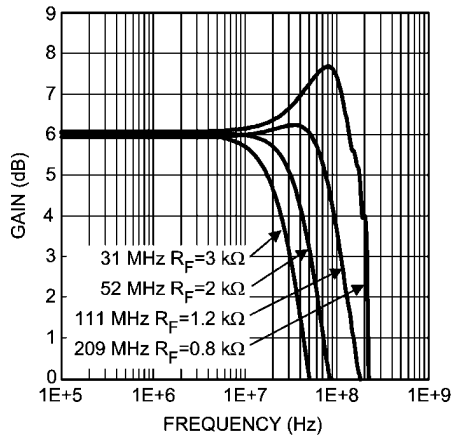
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Gain vs Frequency
 $V_S = \pm 15V, G = -1$



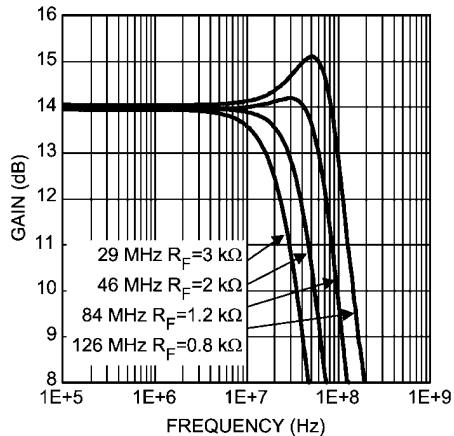
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Gain vs Frequency
 $V_S = \pm 15V, G = -2$



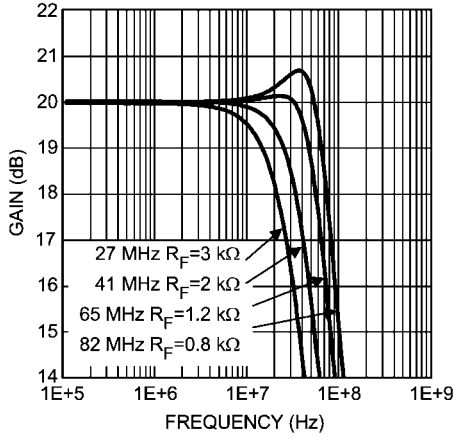
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Gain vs Frequency
 $V_S = \pm 15V, G = -5$



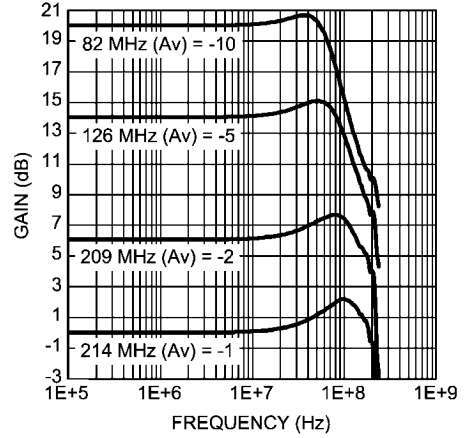
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Gain vs Frequency
 $V_S = \pm 15V, G = -10$



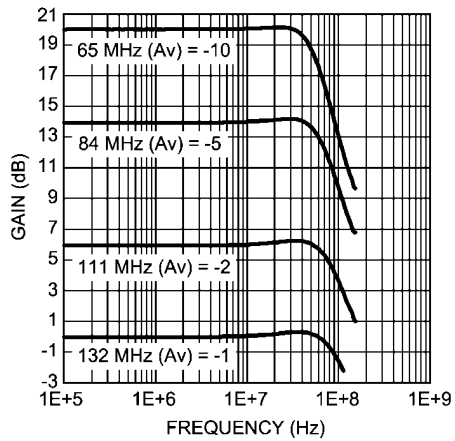
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Gain vs Frequency
 $R_F = 800\Omega, V_S = \pm 15V$



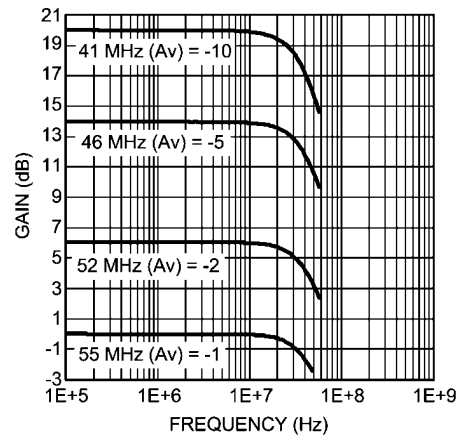
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Gain vs Frequency
 $R_F = 1.2k\Omega, V_S = \pm 15V$



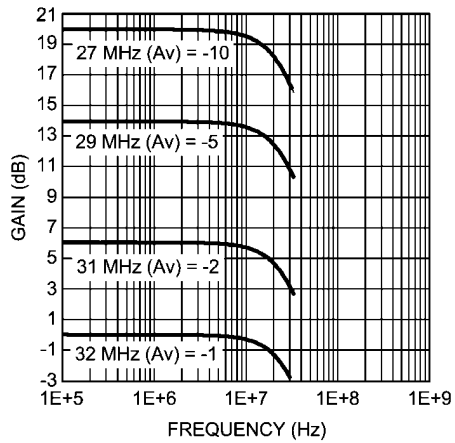
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Gain vs Frequency
 $R_F = 2k\Omega, V_S = \pm 15V$



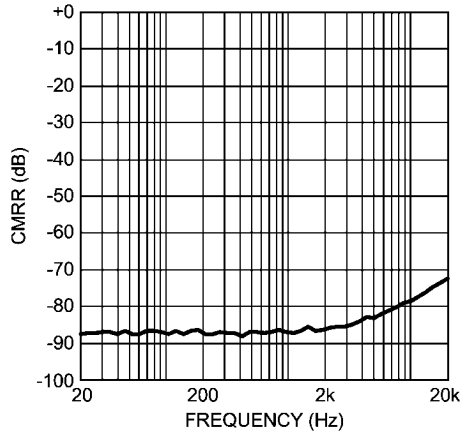
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Gain vs Frequency
 $R_F = 3k\Omega, V_S = \pm 15V$

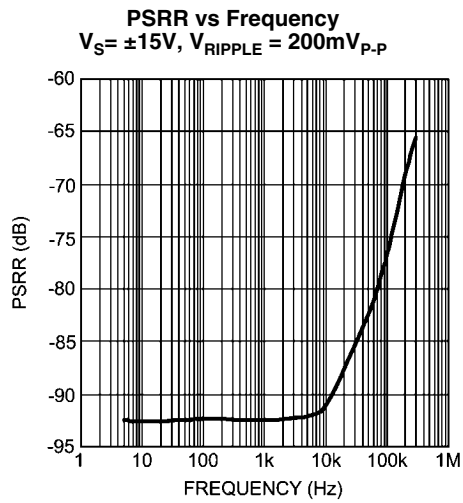


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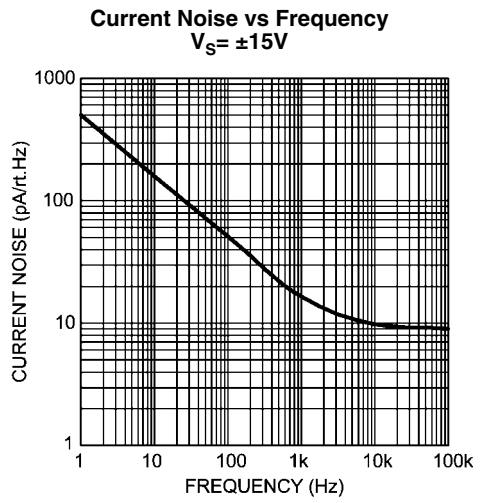
CMRR vs Frequency
 $V_S = \pm 15V$



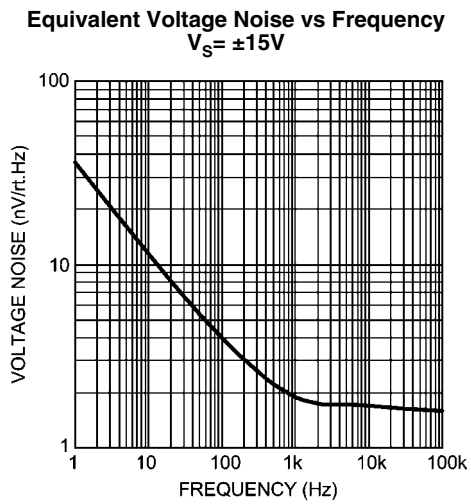
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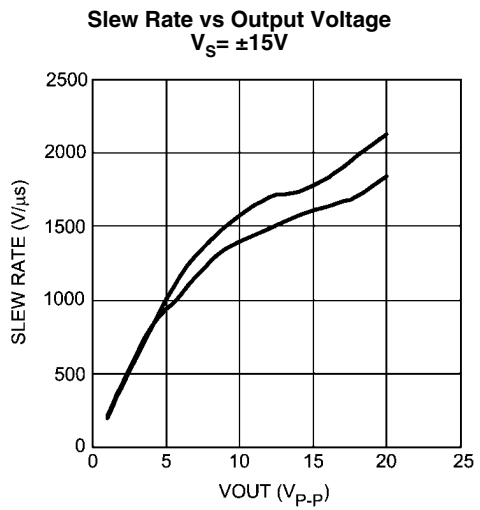
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Application Information

GENERAL AMPLIFIER FUNCTION

Voltage feedback amplifiers have a small-signal bandwidth that is a function of the closed-loop gain. Conversely, the LME49713 current feedback amplifier features a small-signal bandwidth that is relatively independent of the closed-loop gain. This is shown in Figure 1 where the LME49713's gain is -1 , -2 , -5 and -10 . Like all current feedback amplifiers, the LME49713's closed-loop bandwidth is a function of the feedback resistance value. Therefore, R_s must be varied to select the desired closed-loop gain.

POWER SUPPLY BYPASSING AND LAYOUT CONSIDERATIONS

Properly placed and correctly valued supply bypassing is essential for optimized high-speed amplifier operation. The supply bypassing must maintain a wideband, low-impedance capacitive connection between the amplifier's supply pin and ground. This helps preserve high speed signal and fast transient fidelity. The bypassing is easily accomplished using a parallel combination of a $10\mu\text{F}$ tantalum and a $0.1\mu\text{F}$ ceramic capacitors for each power supply pin. The bypass capacitors should be placed as close to the amplifier power supply pins as possible.

FEEDBACK RESISTOR SELECTION (R_f)

The value of the R_f is also a dominant factor in compensating the LME49713. For general applications, the LME49713 will maintain specified performance with an $1.2\text{k}\Omega$ feedback resistor. Although this value will provide good results for most applications, it may be advantageous to adjust this value slightly for best pulse response optimized for the desired bandwidth. In addition to reducing bandwidth, increasing the feedback resistor value also reduces overshoot in the time domain response.

SLEW RATE CONSIDERATIONS

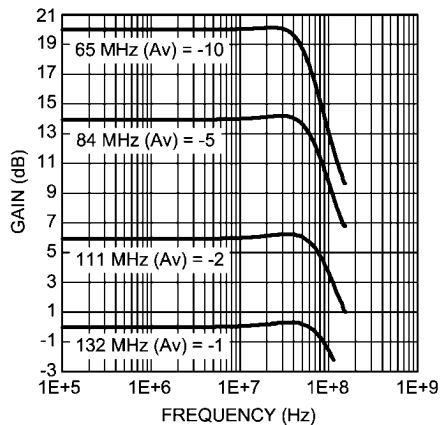
A current feedback amplifier's slew rate characteristics are different than that of voltage feedback amplifiers. A voltage feedback amplifier's slew rate limiting or non-linear amplifier behavior is dominated by the finite availability of the first stage tail current charging the second stage voltage amplifier's compensation capacitor. Conversely, a current feedback amplifier's slew rate is not constant. Transient current at the inverting input determines slew rate for both inverting and non-inverting gains. The non-inverting configuration slew rate is also determined by input stage limitations. Accordingly, variations of slew rates occur for different circuit topologies.

DRIVING CAPACITIVE LOADS

The LME49713 can drive significantly higher capacitive loads than many current feedback amplifiers. Although the LME49713 can directly drive as much as 100pF without oscillating, the resulting response will be a function of the feedback resistor value.

CAPACITIVE FEEDBACK

It is quite common to place a small lead-compensation capacitor in parallel with a voltage feedback amplifier's feedback resistance, R_f . This compensation reduces the amplifier's peaking in the frequency domain and damps the transient response. Whereas this yields the expected results when used with voltage feedback amplifiers, this technique must not be used with current feedback amplifiers. The dynamic impedance of capacitors in the feedback loop reduces the amplifier's stability. Instead, reduced peaking in the frequency response and bandwidth limiting can be accomplished by adding an RC circuit to the amplifier's input.



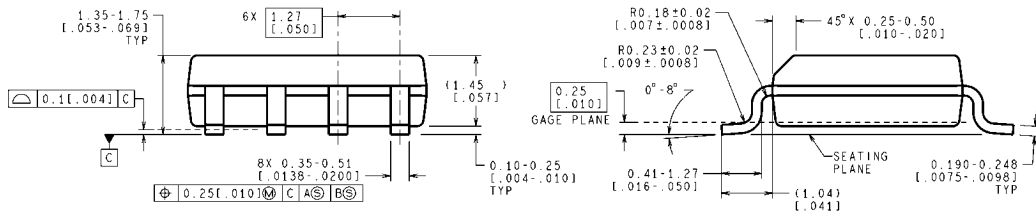
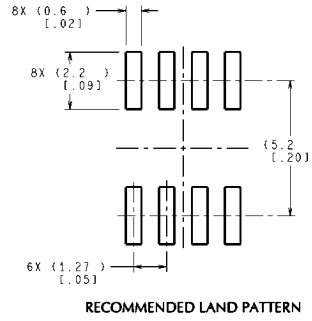
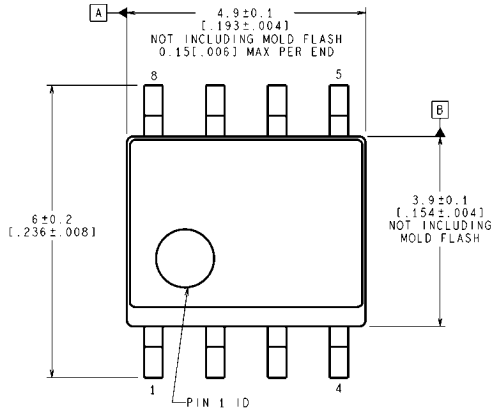
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FIGURE 1. Bandwidth as a function of gain

Revision History

Rev	Date	Description
1.0	09/26/07	Initial release.
1.1	09/28/07	Added the Typical Performance curves.
1.2	10/03/07	Input Limit values.
1.3	10/29/07	Edited the Specification table, typical performance curve, and text edits.
1.4	01/29/08	Added more curves in the Typical Performance section.
1.5	07/24/08	Added the Metal Can package.
1.6	08/20/08	Text edits (updated some of the curves' titles).
1.7	08/22/08	Text edits.

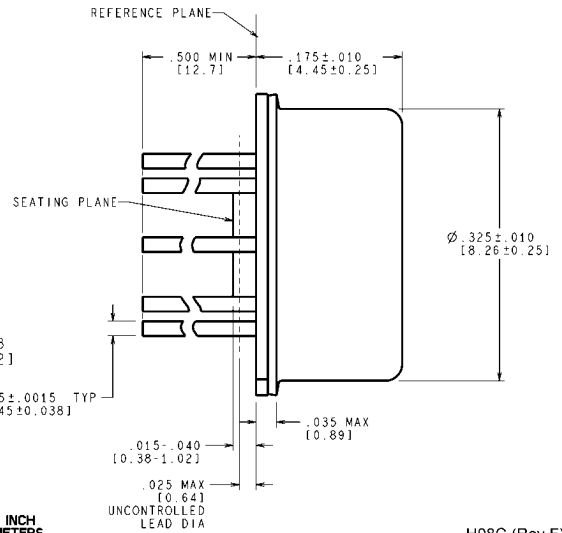
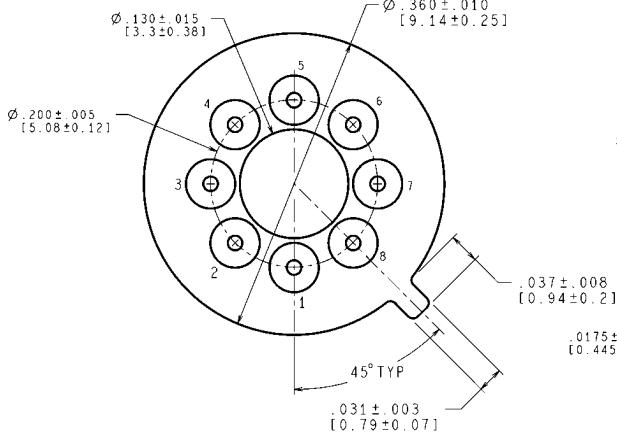
Physical Dimensions inches (millimeters) unless otherwise noted



CONTROLLING DIMENSION IS MILLIMETER
VALUES IN [] ARE INCHES
DIMENSIONS IN () FOR REFERENCE ONLY

M08A (Rev L)

SOIC Package
Order Number LME49713MA
NS Package Number M08A



CONTROLLING DIMENSION IS INCH
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H08C (Rev F)

Metal Can
Order Number LME49713HA
NS Package Number H08C

Notes

Notes

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